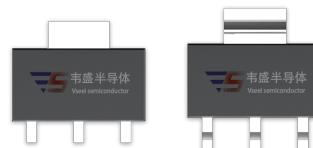


## DESCRIPTION:

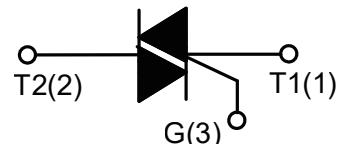
The Z0107NN SCR series with the parallel resistor between Gate and Cathode are especially recommended for use on straight hair, igniter, anion generator, etc.



SOT-89      SOT-223

## MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	1	A
$I_{TSM}$	16	A
$V_{TM}$	$\leq 1.5$	V



## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40 - 150	°C
Operating junction temperature range	$T_j$	-40 - 125	°C
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )	$V_{DRM}$	600/800	V
Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )	$V_{RRM}$	600/800	V
RMS on-state current SOT-223/ SOT-89/ SOT-223-2L ( $T_c=75^\circ\text{C}$ )	$I_{T(RMS)}$	1	A
Non repetitive surge peak on-state current (full cycle, $F=50\text{Hz}$ )	$I_{TSM}$	16	A
$I^2t$ value for fusing ( $t_p=10\text{ms}$ )	$I^2t$	1.28	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}$ )	$dI/dt$	20	$\text{A}/\mu\text{s}$
Peak gate current	$I_{GM}$	2	A
Average gate power dissipation	$P_{G(AV)}$	0.5	W
Peak gate power	$P_{GM}$	5	W

**ELECTRICAL CHARACTERISTICS (T<sub>j</sub>=25°C unless otherwise specified)**

<b>Symbol</b>	<b>Test Condition</b>	<b>Quadrant</b>		<b>Value</b>		<b>Unit</b>
				<b>T</b>	<b>D</b>	
I <sub>GT</sub>	V <sub>D</sub> =12V R <sub>L</sub> =33Ω	I - II - III	MAX	5	5	mA
		IV		5	10	
V <sub>GT</sub>	ALL		MAX	1.3		V
V <sub>GD</sub>	V <sub>D</sub> =V <sub>DRM</sub> T <sub>j</sub> =125°C R <sub>L</sub> =3.3KΩ	ALL	MIN	0.2		V
I <sub>L</sub>	I <sub>G</sub> =1.2I <sub>GT</sub>	I - III	MAX	5	5	mA
		II - IV		10	20	
I <sub>H</sub>	I <sub>T</sub> =200mA		MAX	5	7	mA
dV/dt	V <sub>D</sub> =2/3V <sub>DRM</sub> Gate Open T <sub>j</sub> =125°C		MIN	15	20	V/μs

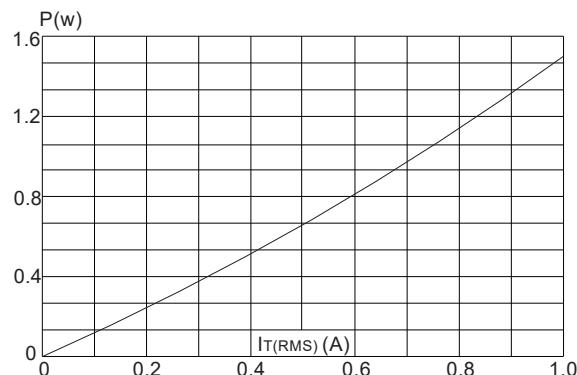
**STATIC CHARACTERISTICS**

<b>Symbol</b>	<b>Parameter</b>		<b>Value(MAX)</b>	<b>Unit</b>
V <sub>TM</sub>	I <sub>TM</sub> =1.4A tp=380μs	T <sub>j</sub> =25°C	1.5	V
I <sub>DRM</sub>	V <sub>D</sub> =V <sub>DRM</sub> V <sub>R</sub> =V <sub>RRM</sub>	T <sub>j</sub> =25°C	5	μA
I <sub>RRM</sub>		T <sub>j</sub> =125°C	500	μA

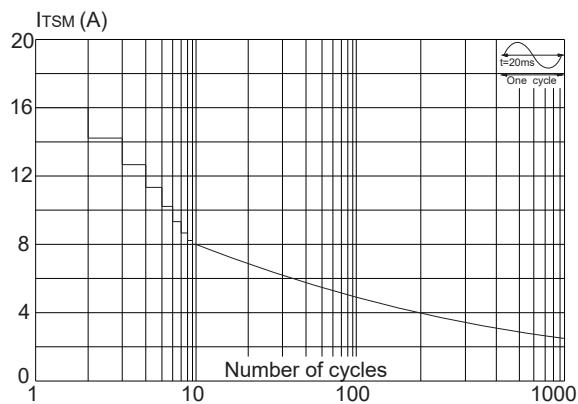
**THERMAL RESISTANCES**

<b>Symbol</b>	<b>Parameter</b>		<b>Value</b>	<b>Unit</b>
R <sub>th(j-c)</sub>	junction to case(AC)	SOT-223/ SOT-89-2L/ SOT-223-2L	31	°C/W
R <sub>th(j-a)</sub>	junction to ambient	SOT-89-2L	64	°C/W
		SOT-223/ SOT-223-2L	60	

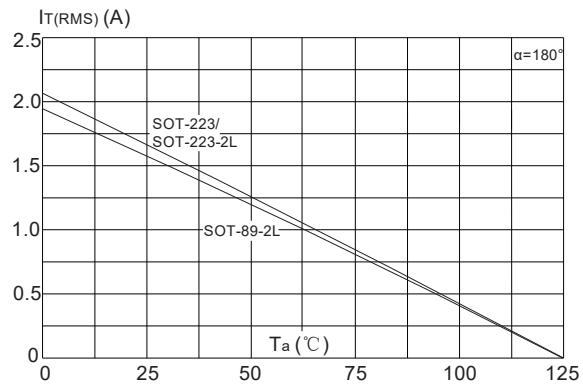
**FIG.1:** Maximum power dissipation versus RMS on-state current



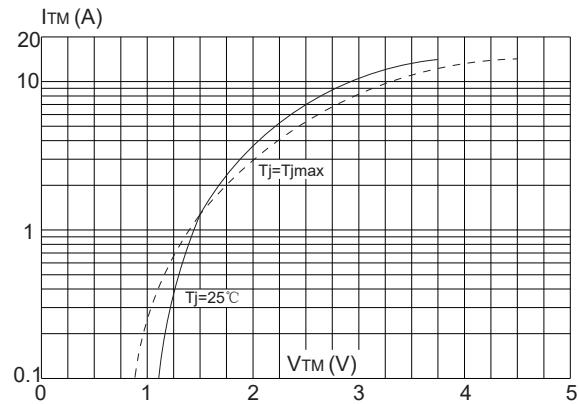
**FIG.3:** Surge peak on-state current versus number of cycles



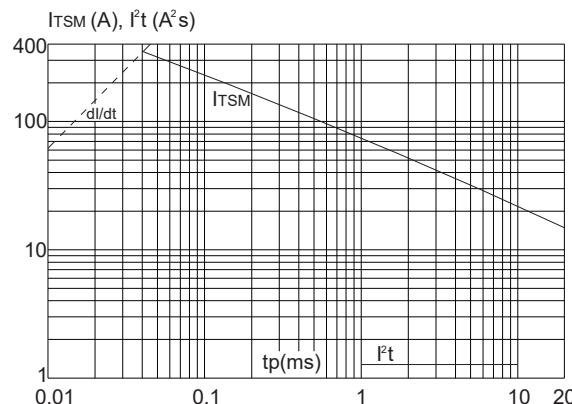
**FIG.2:** RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35μm) (full cycle )



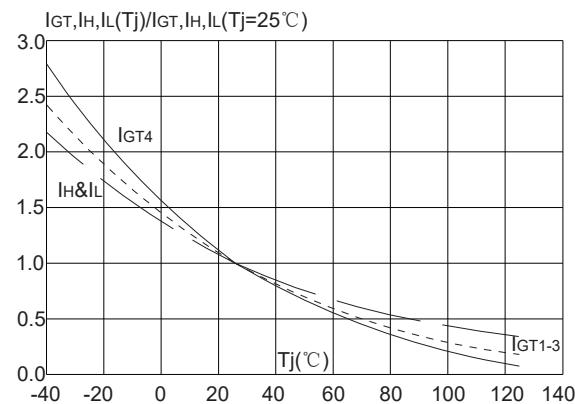
**FIG.4:** On-state characteristics (maximum values)



**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20\text{ms}$  and corresponding value of  $I^2t$  ( $dI/dt < 20\text{A}/\mu\text{s}$ )



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature



## SOLDERING PARAMETERS

Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min ( $T_{s(\min)}$ )	+150°C
	-Temperature Max( $T_{s(\max)}$ )	+200°C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquidus Temp ( $T_L$ ) to peak)		3°C/sec. Max
$T_{s(\max)}$ to $T_L$ - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature( $T_L$ ) (Liquidus)	+217°C
	-Temperature( $t_L$ )	60-150 secs.
Peak Temp ( $T_p$ )		+260(+0/-5)°C
Time within 5°C of actual Peak Temp ( $t_p$ )		20-40secs.
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp ( $T_p$ )		8 min. Max
Do not exceed		+260°C

